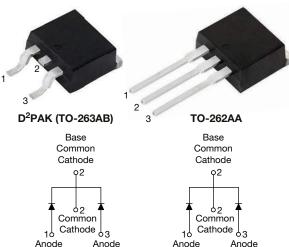
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VS-16CTU04S-M3, VS-16CTU04-1-M3

Vishay Semiconductors

Ultrafast Rectifier, 16 A FRED Pt[®]



Anode Anode VS-16CTU04S-M3

VS-16CTU04-1-M3

PRIMARY CHARACTERISTICS							
I _{F(AV)}	2 x 8 A						
V _R	400 V						
V _F at I _F	0.94 V						
t _{rr} typ.	35 ns						
T _J max.	175 °C						
Package	D ² PAK (TO-263AB), TO-262AA						
Circuit configuration	Common cathode						

FEATURES

- · Ultrafast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Vishay Semiconductors FRED Pt® series are the state of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Peak repetitive reverse voltage	V _{RRM}		400	V					
per leg	1		8						
Average rectified forward current total device	IF(AV)	Rated V _R , T _C = 155 °C	16						
Non-repetitive peak surge current	I _{FSM}	T _C = 25 °C	100	A					
Peak repetitive forward current	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 155 °C	16						
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C					

ELECTRICAL SPECIFICATIONS PER LEG ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	400	-	-		
Forward valtage	V	I _F = 8 A	-	1.19	1.3	V	
Forward voltage	V _F	I _F = 8 A, T _J = 150 °C	-	0.94	1.0		
Reverse leakage current		$V_{R} = V_{R}$ rated	-	0.2	10		
Reverse leakage current	I _R	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	20	500	μA	
Junction capacitance	CT	V _R = 400 V	-	14	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH	

RoHS COMPLIANT HALOGEN FREE

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DYNAMIC RECOVERY CHARACTERISTICS PER LEG ($T_J = 25$ °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	50 A/µA, V _R = 30 V	-	35	60			
Reverse recovery time	t _{rr}	T _J = 25 °C		-	43	-	ns		
		T _J = 125 °C		-	67	-			
Deals receivers ourrent	I _{RRM}	T _J = 25 °C	I _F = 8 A dI _F /dt = 200 A/μs V _R = 200 V	-	2.8	-	А		
Peak recovery current		T _J = 125 °C		-	6.3	-	A		
D	Q _{rr}	T _J = 25 °C		-	60	-	-		
Reverse recovery charge		T _J = 125 °C		-	210	-	nC		

THERMAL - MECHANIC	AL SPECIFI	CATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C
Thermal resistance, junction to case per leg	R _{thJC}		-	1.8	2.0	
Thermal resistance, junction to ambient per leg	R _{thJA}	Typical socket mount	-	-	50	°C/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-	
Weight			-	2.0	-	g
Weight			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking davias		Case style D ² PAK (TO-263AB)		16CT	175 °C 2.0	
Marking device		Case style TO-262AA		16CT	U04-1	

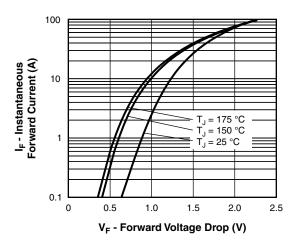


Fig. 1 - Typical Forward Voltage Drop Characteristics

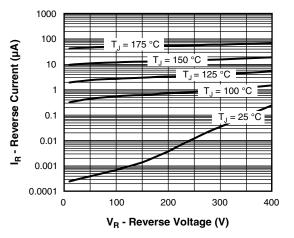


Fig. 2 - Typical Values of Reverse Current vs.Reverse Voltage

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VS-16CTU04S-M3, VS-16CTU04-1-M3

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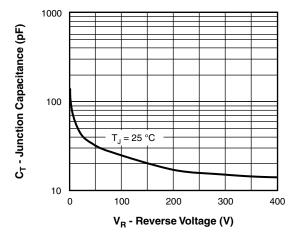


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

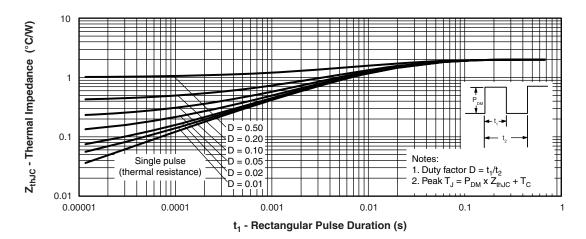
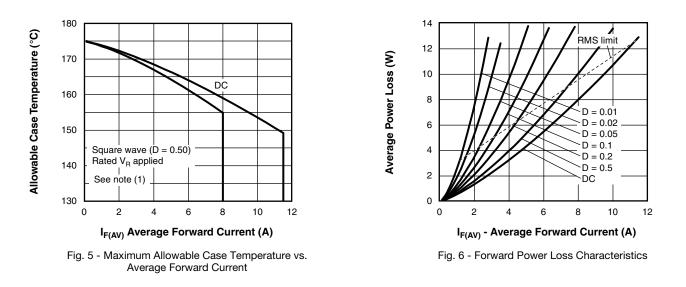


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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Note

 $^{(1)} \mbox{ Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}; \\ Pd = \mbox{forward power loss} = I_{F(AV)} \times V_{FM} \mbox{ at } (I_{F(AV)}/D) \mbox{ (see fig. 6); } \\ Pd_{REV} = \mbox{inverse power loss} = V_{R1} \times I_R \mbox{ (1 - D); } I_R \mbox{ at } V_{R1} = \mbox{rated } V_R$

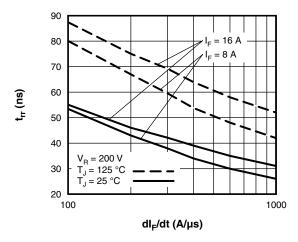


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

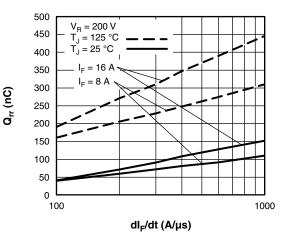


Fig. 8 - Typical Stored Charge vs. dl_F/dt

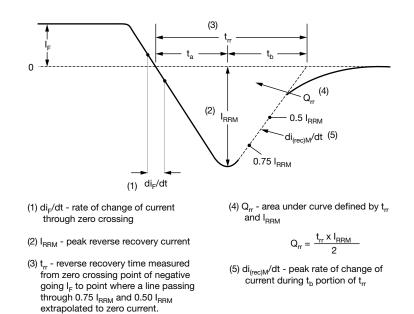
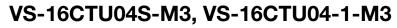


Fig. 9 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE

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SHAY

Device code	VS-	16	С	т	U	04	S	TRL	-M3
		(2)	(3)	(4)	(5)	6			(9)
	\bigcirc		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\mathbf{O}	U	U
	<u>п</u> .	Visl	nay Sem	nicondua	ctors pro	oduct			
	2 -		rent rati			Judot			
	3 -		commo						
	4 -		TO-220			334B)			
	5 -		ultrafas			50/10)			
					•				
	6 -		age rati	•					
	7 -		= D ² PA	•	63AB)				
	_	• -1	= TO-2	62AA					
	8 -	• N	one = tu	be (50 p	oieces)				
		• TI	RL = tap	e and re	el (left	orientec	l, for D ²	PAK (T	O-263A
		• TI	R = tap	e and r	eel (righ	t orient	ed, for I	D ² PAK ((TO-263
	9.	- Env	vironmer	ntal digit	:				
		-M3	8 = halog	gen-free	, RoHS	-complia	ant, and	termina	ations le

ORDERING INFORMATION (Example)							
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION					
VS-16CTU04S-M3	50	Antistatic plastic tubes					
VS-16CTU04STRL-M3	800	13" diameter plastic tape and reel					
VS-16CTU04STRR-M3	800	13" diameter plastic tape and reel					
VS-16CTU04-1-M3	50	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS							
Dimonsions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164					
Dimensions	TO-262AA	www.vishay.com/doc?96165					
Port marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444					
Part marking information	TO-262AA	www.vishay.com/doc?95443					
SPICE model		www.vishay.com/doc?96565					

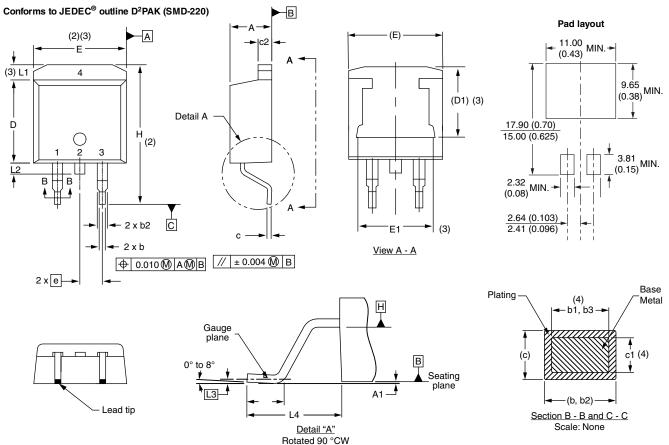
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D²PAK

DIMENSIONS in millimeters and inches

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ISHA





SYMBOL	MILLIM	MILLIMETERS		HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100) BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 13-Jul-17

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Document Number: 96164

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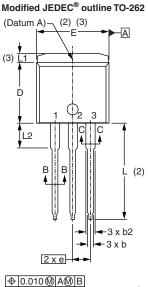
Outline Dimensions

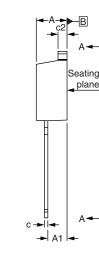


Vishay Semiconductors

TO-262AA

DIMENSIONS in millimeters and inches



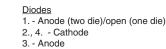


D1 (3) (3) Section A - A Base (4) Plating b1. b3 metal ≰ c1 (4) -(b, b2)-Section B - B and C - C Scale: None

E

010	(M) A	.@/E	3		
_				_	
	math	math.	mark		





Lead assignments

SYMBOL	MILLIN	METERS	INC	INCHES		
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54	BSC	0.100) BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

Notes

 ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
 ⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the second flash include mold flash. the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

(6) Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)

Revision: 30-Nov-17

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